



BC807-16W/ -25W/ -40W

45V PNP SMALL SIGNAL TRANSISTOR IN SOT323

Features

- Ideally Suited for Automatic Insertion
- Epitaxial Planar Die Construction
- Complementary NPN Types Available (BC817-xxW)
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

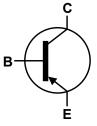
Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.006 grams (approximate)

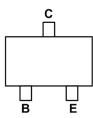


SOT323

Top View







Top View Pin-Out

Ordering Information (Notes 4)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BC807-16W-7	K5A	7	8	3,000
BC807-25W-7	K5B	7	8	3,000
BC807-40W-7	K5C	7	8	3,000

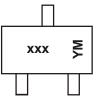
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



xxx = Product Type Marking Code (Please see Ordering Information)
YM = Date Code Marking
Y = Year ex: X = 2010
M = Month ex: 9 = September

Date Code Key

Year	2010	2	011	2012	2	2013	2014		2015	2016		2017
Code	Х		Y	Z		А	В		С	D		E
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-45	V
Emitter-Base Voltage	V _{EBO}	-5	V
Continuous Collector Current	Ι _C	-500	mA
Peak Collector Current	I _{CM}	-1.0	A
Peak Base Current	I _{BM}	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient (Note 5)		R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J ,T _{STG}	-65 to +150	٥C	

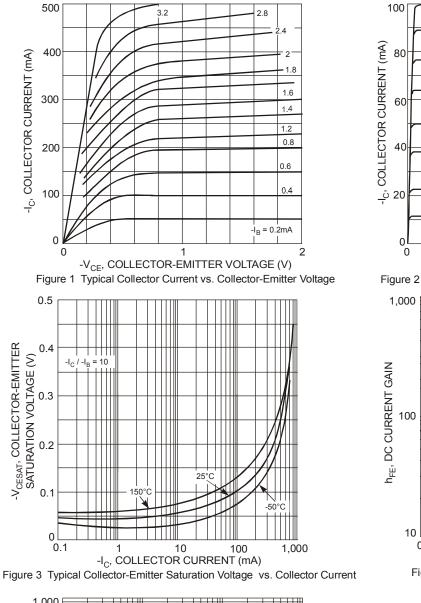
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

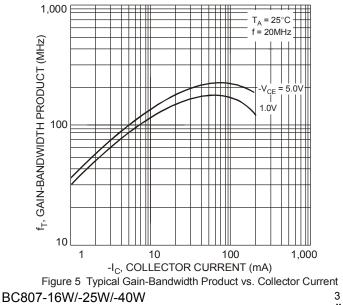
Characteristic			Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage			-45	—	—	V	I _c = -10mA
Emitter-Base Breakdown Voltage			-5		_	V	I _C = -100μA
Collector-Emitter Cutoff Current		I _{CES}	_	_	-100 -5.0	nA μA	V _{CE} = -45V V _{CE} = -25V, T _J = +150°C
Collector	I _{CBO}	_	_	-100 -5.0	nA μA	V _{CB} = -20V V _{CB} = -20V, T _J = +150°C	
Emitter-Base Cutoff Current		I _{EBO}	_	-	-100	nA	V _{EB} = -5V
DC Current Gain (Note 6)	BC807-16W-7 BC807-25W-7 BC807-40W-7	Ŀ	100 160 250		250 400 600		I _C = -100mA, V _{CE} = -1.0V
	BC807-16W-7 BC807-25W-7 BC807-40W-7	h _{FE}	60 100 170		_		I _C = -300mA, V _{CE} = -1.0V
Collector-Emitter Saturation Volt	V _{CE(sat)}	_	_	-700	mV	I _C = -500mA, I _B = -50mA	
Base-Emitter Voltage (Note 6)	V _{BE}		_	-1200	mV	I _C = -300mA, V _{CE} = -1.0V	
Gain Bandwidth Product		f _T	100	_	_	MHz	V_{CE} = -5.0V, I _C = -10mA, f = 50MHz
Collector-Base Capacitance	C _{CBO}			12	pF	V _{CB} = -10V, f = 1.0MHz	

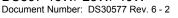
5. For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state. 6. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



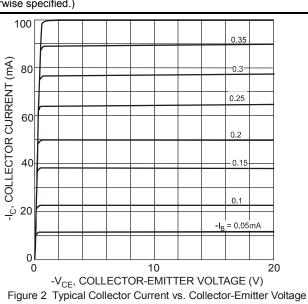


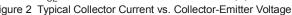


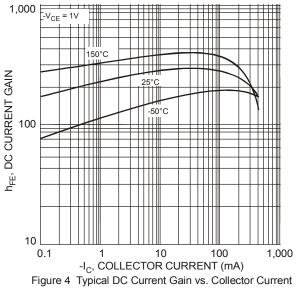




3 of 5 www.diodes.com



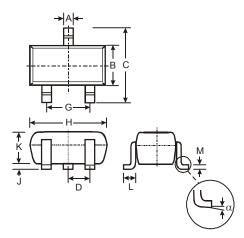






Package Outline Dimensions

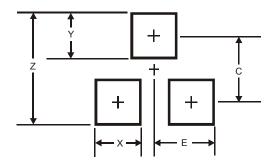
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT323						
Dim	Min	Max	Тур			
Α	0.25	0.40	0.30			
В	1.15	1.35	1.30			
С	2.00	2.20	2.10			
D	-	-	0.65			
G	1.20	1.40	1.30			
н	1.80	2.20	2.15			
J	0.0	0.10	0.05			
К	0.90	1.00	1.00			
L	0.25	0.40	0.30			
М	0.10	0.18	0.11			
α	0°	8°	-			
All	All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
E	1.0



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

- 1. are intended to implant into the body, or
- 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013, Diodes Incorporated

www.diodes.com